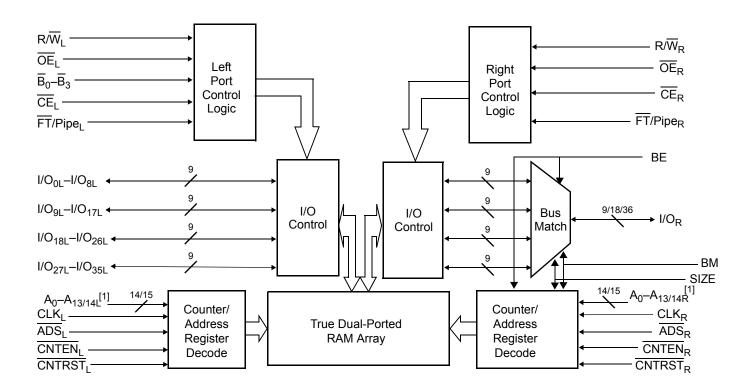


# **Logic Block Diagram**



<sup>1.</sup>  $A_0$ - $A_{13}$  for 16K;  $A_0$ - $A_{14}$  for 32K devices.



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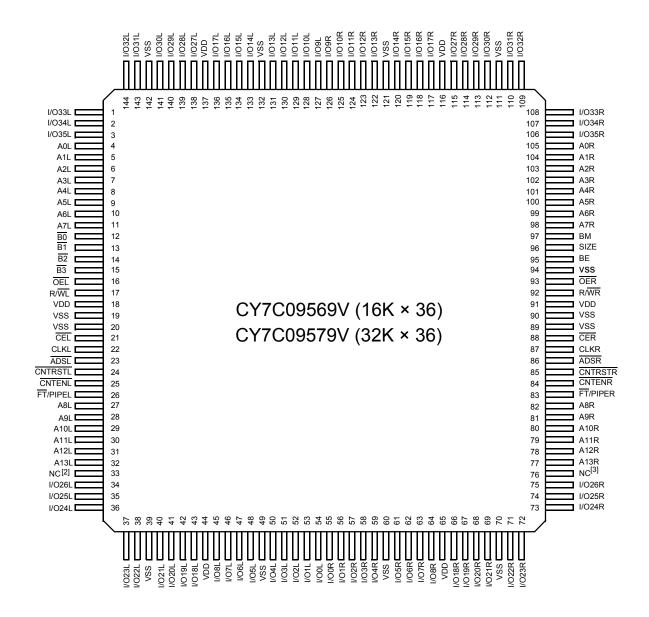
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# **Pin Configurations**

Figure 1. 144-pin TQFP (20 × 20 × 1.4 mm) pinout (Top View)



- 2. This pin is A14L for CY7C09579V.
- 3. This pin is A14R for CY7C09579V.



# Pin Configurations (continued)

Figure 2. 172-ball BGA (15 × 15 × 1.25 mm) pinout (Top View)

| _ | 1        | 2                 | 3      | 4       | 5      | 6      | 7      | 8      | 9      | 10     | 11      | 12     | 13                | 14       |
|---|----------|-------------------|--------|---------|--------|--------|--------|--------|--------|--------|---------|--------|-------------------|----------|
| Α | I/O32L   | I/O30L            | NC     | VSS     | I/O13L | VDD    | I/O11L | I/011R | VDD    | I/O13R | VSS     | NC     | I/O30R            | I/O32R   |
| В | A0L      | I/O33L            | I/O29  | I/O17L  | I/O14L | I/O12L | I/O9L  | I/09R  | I/O12R | I/O14R | I/O17R  | I/O29R | I/033R            | A0R      |
| С | NC       | A1L               | I/O31L | I/O27L  | NC     | I/O15L | I/O10L | I/O10R | I/O15R | NC     | I/027R  | I/O31R | A1R               | NC       |
| D | A2L      | A3L               | I/O35L | I/O34L  | I/O28L | I/O16L | VSS    | VSS    | I/O16R | I/O28R | I/O34R  | I/O35R | A3R               | A2R      |
| Е | A4L      | A5L               | NC     | B0L     | NC     | NC     |        | •      | NC     | NC     | BM      | NC     | A5R               | A4R      |
| F | VDD      | A6L               | A7L    | B1L     | NC     |        | •      |        |        | NC     | SIZE    | A7R    | A6R               | VDD      |
| G | OEL      | B2L               | B3L    | CEL     |        |        |        |        |        |        | CER     | VSS    | BE                | OER      |
| Н | VSS      | R/WL              | A8L    | CLKL    |        |        |        |        |        |        | CLKR    | A8R    | R/WR              | VSS      |
| J | A9L      | A10L              | VSS    | ADSL    | NC     |        |        |        |        | NC     | ADSR    | VSS    | A10R              | A9R      |
| K | A11L     | A12L              | NC     | CNTRSTL | NC     | NC     |        |        | NC     | NC     | CNTRSTR | NC     | A12R              | A11R     |
| L | FT/PIPEL | A13L              | CNTENL | I/O26L  | I/O25L | I/O19L | VSS    | VSS    | I/O19R | I/O25R | I/O26R  | CNTENR | A13R              | FT/PIPER |
| M | NC       | NC <sup>[4]</sup> | I/O22L | I/O18L  | NC     | I/O7L  | I/O2L  | I/02R  | I/07R  | NC     | I/O18R  | I/O22R | NC <sup>[5]</sup> | NC       |
| N | I/O24L   | I/O20L            | I/O8L  | I/O6L   | I/O5L  | I/O3L  | I/O0L  | I/O0R  | I/O3R  | I/O5R  | I/06R   | I/O8R  | I/O20R            | I/O24R   |
| Р | I/O23L   | I/O21L            | NC     | VSS     | I/O4L  | VDD    | I/O1L  | I/O1R  | VDD    | I/04R  | VSS     | NC     | I/021R            | I/O23R   |

Notes
4. This pin is A14L for CY7C09579V.
5. This pin is A14R for CY7C09579V.



# **Pin Definitions**

| Left Port                                 | Right Port                            | Description  |  |  |  |  |  |
|---|---------------------------------------|--|--|--|--|--|--|
| A <sub>0L</sub> -A <sub>13/14L</sub>      | A <sub>0R</sub> -A <sub>13/14R</sub>  | Address Inputs (A <sub>0</sub> –A <sub>13</sub> for 16K, A <sub>0</sub> –A <sub>14</sub> for 32K devices).   |  |  |  |  |  |
| ADS <sub>L</sub>                          | ADS <sub>R</sub>                      | Address Strobe Input. Used as an address qualifier. This signal should be asserted LOW to assert the part using the externally supplied address on Address Pins. To load this address into the Burst Address Counter both ADS and CNTEN have to be LOW. ADS is disabled if CNTRST is asserted LOW. |  |  |  |  |  |
| CEL                                       | CE <sub>R</sub>                       | Chip Enable Input.   |  |  |  |  |  |
| CLK <sub>L</sub>                          | CLK <sub>R</sub>                      | Clock Signal. This input can be free-running or strobed. Maximum clock input rate is f <sub>MAX</sub> .  |  |  |  |  |  |
| CNTENL                                    | CNTEN <sub>R</sub>                    | Counter Enable Input. Asserting this signal LOW increments the burst address counter of its respective port on each rising edge of CLK. CNTEN is disabled if CNTRST is asserted LOW.   |  |  |  |  |  |
| CNTRST <sub>L</sub>                       | CNTRST <sub>R</sub>                   | Counter Reset Input. Asserting this signal LOW resets the burst address counter of its respective port to zero. CNTRST is not disabled by asserting ADS or CNTEN.  |  |  |  |  |  |
| I/O <sub>0L</sub> –I/O <sub>35L</sub>     | I/O <sub>0R</sub> –I/O <sub>35R</sub> | Data Bus Input/Output  |  |  |  |  |  |
| ŌĒL                                       | ŌĒ <sub>R</sub>                       | Output Enable Input. This signal must be asserted LOW to enable the I/O data pins during read operations.  |  |  |  |  |  |
| $R/\overline{W}_L$                        | R/W <sub>R</sub>                      | Read/Write Enable Input. This signal is asserted LOW to write to the dual port memory array. For read operations, assert this pin HIGH.  |  |  |  |  |  |
| FT/PIPE <sub>L</sub>                      | FT/PIPE <sub>R</sub>                  | Flow-Through/Pipelined Select Input. For flow-through mode operation, assert this pin LOW. For pipelined mode operation, assert this pin HIGH.   |  |  |  |  |  |
| $\overline{B}_{0L}$ – $\overline{B}_{3L}$ | _                                     | Byte Select Inputs. Asserting these signals enable read and write operations to the corresponding bytes of the memory array.   |  |  |  |  |  |
| _   | BM, SIZE                              | Select Pins for Bus Matching. See Bus Matching for details.  |  |  |  |  |  |
| _   | BE                                    | Big Endian Pin. See Bus Matching for details.  |  |  |  |  |  |
| $V_{SS}$                                  |                                       | Ground Input.  |  |  |  |  |  |
| $V_{DD}$                                  |                                       | Power Input.   |  |  |  |  |  |



# **Maximum Ratings**

Exceeding maximum ratings<sup>[6]</sup> may shorten the useful life of the device. User guidelines are not tested. Ambient temperature with Supply voltage to ground potential .....-0.5 V to +4.6 V DC voltage applied to outputs in High Z state ......-0.5 V to V<sub>DD</sub> + 0.5 V

| DC input voltage <sup>[7]</sup>   | 0.5 V to V <sub>DD</sub> + 0.5 V |
|-----------------------------------|----------------------------------|
| Output current into outputs (LOW) | 20 mA                            |
| Static discharge voltage          | > 2001 V                         |
| Latch-up current                  | > 200 mA                         |

## **Operating Range**

| Range      | Ambient Temperature | $V_{DD}$         |  |  |
|------------|---------------------|------------------|--|--|
| Commercial | 0 °C to +70 °C      | $3.3~V\pm165~mV$ |  |  |

## **Electrical Characteristics**

Over the Operating Range

|                  |  | CY7C09569V / CY7C09579V |      |     |     |      |     |    |  |  |
|------------------|--|-------------------------|------|-----|-----|------|-----|----|--|--|
| Parameter        | Description  |                         | -100 |     |     | Unit |     |    |  |  |
|                  |  | Min                     | Тур  | Max | Min | Тур  | Max |    |  |  |
| V <sub>OH</sub>  | Output HIGH Voltage<br>(V <sub>DD</sub> = Min., I <sub>OH</sub> = -4.0 mA)   | 2.4                     | _    | _   | 2.4 | _    | _   | V  |  |  |
| V <sub>OL</sub>  | Output LOW Voltage<br>(V <sub>DD</sub> = Min., I <sub>OL</sub> = +4.0 mA)  | _                       | _    | 0.4 | _   | _    | 0.4 | V  |  |  |
| V <sub>IH</sub>  | Input HIGH Voltage   | 2.0                     | _    | _   | 2.0 | -    | _   | V  |  |  |
| V <sub>IL</sub>  | Input LOW Voltage  | _                       | _    | 0.8 | _   | -    | 0.8 | V  |  |  |
| I <sub>OZ</sub>  | Output Leakage Current   | -10                     | _    | 10  | -10 | _    | 10  | μА |  |  |
| Icc              | Operating Current<br>(V <sub>DD</sub> = Max., I <sub>OUT</sub> = 0 mA)<br>Outputs Disabled   | -                       | 250  | 385 | _   | 240  | 360 | mA |  |  |
| I <sub>SB1</sub> | $\frac{\underline{Sta} ndb \underline{y} \ \underline{C} urrent \ (Both \ Ports \ TTL \ Level)}{\underline{CE}_L \ \& \ \underline{CE}_R \ge V_{IH}, \ f = f_{MAX}}$ | _                       | 30   | 75  | -   | 25   | 70  | mA |  |  |
| I <sub>SB2</sub> | $\frac{\underline{Sta} \underline{ndby} \ \underline{Current} \ (One \ Port \ TTL \ Level)}{\underline{CE}_L \   \ \underline{CE}_R \ge V_{IH}, \ f = f_{MAX}}$      | _                       | 170  | 220 | _   | 160  | 210 | mA |  |  |
| I <sub>SB3</sub> |  | _                       | 0.01 | 1   | _   | 0.01 | 1   | mA |  |  |
| I <sub>SB4</sub> | Standby Current<br>(One Port CMOS Level)<br>$\overline{CE}_L \mid \overline{CE}_R \ge V_{IH}$ , $f = f_{MAX}$  | _                       | 150  | 200 | _   | 140  | 190 | mA |  |  |

The voltage on any input or I/O pin can not exceed the power pin during power-up.
 Pulse width < 20 ns.</li>

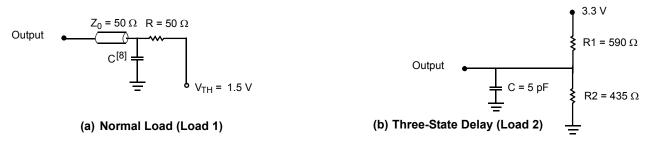


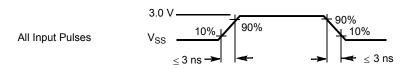
# Capacitance

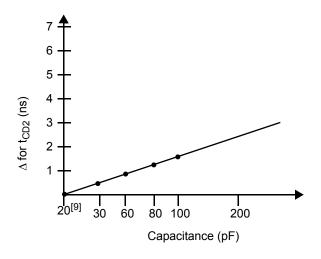
| Parameter        | Description        | Test Conditions  | Max | Unit |
|------------------|--------------------|--|-----|------|
| C <sub>IN</sub>  | Input capacitance  | $T_A = 25 ^{\circ}\text{C}, f = 1 \text{MHz}, V_{DD} = 3.3 \text{V}$ | 10  | pF   |
| C <sub>OUT</sub> | Output capacitance |  | 10  | pF   |

## **AC Test Load and Waveforms**

Figure 3. AC Test Load and Waveforms







(b) Load Derating Curve

- 8. External AC Test Load Capacitance = 10 pF.
- 9. (Internal I/O pad Capacitance = 10 pF + AC Test Load.



# **Switching Characteristics**

Over the Operating Range

|                   |                                 | C   | CY7C09569V/CY7C09579V |     |     |      |  |  |
|-------------------|---------------------------------|-----|-----------------------|-----|-----|------|--|--|
| Parameter         | Description                     | -1  | -100                  |     |     | Unit |  |  |
|                   |                                 | Min | Max                   | Min | Max |      |  |  |
| f <sub>MAX1</sub> | f <sub>Max</sub> Flow-Through   | _   | 67                    | _   | 45  | MHz  |  |  |
| f <sub>MAX2</sub> | f <sub>Max</sub> Pipelined      | _   | 100                   | _   | 83  | MHz  |  |  |
| t <sub>CYC1</sub> | Clock Cycle Time – Flow-Through | 15  | _                     | 22  | _   | ns   |  |  |
| t <sub>CYC2</sub> | Clock Cycle Time – Pipelined    | 10  | _                     | 12  | _   | ns   |  |  |
| t <sub>CH1</sub>  | Clock HIGH Time – Flow-Through  | 6.5 | _                     | 7.5 | _   | ns   |  |  |
| t <sub>CL1</sub>  | Clock LOW Time – Flow-Through   | 6.5 | _                     | 7.5 | _   | ns   |  |  |
| t <sub>CH2</sub>  | Clock HIGH Time – Pipelined     | 4   | _                     | 5   | _   | ns   |  |  |
| t <sub>CL2</sub>  | Clock LOW Time – Pipelined      | 4   | _                     | 5   | _   | ns   |  |  |
| t <sub>R</sub>    | Clock Rise Time                 | _   | 3                     | _   | 3   | ns   |  |  |
| t <sub>F</sub>    | Clock Fall Time                 | _   | 3                     | _   | 3   | ns   |  |  |
| t <sub>SA</sub>   | Address Set-Up Time             | 3.5 | _                     | 4   | _   | ns   |  |  |
| t <sub>HA</sub>   | Address Hold Time               | 0.5 | _                     | 0.5 | _   | ns   |  |  |
| t <sub>SB</sub>   | Byte Select Set-Up Time         | 3.5 | _                     | 4   | _   | ns   |  |  |
| t <sub>HB</sub>   | Byte Select Hold Time           | 0.5 | _                     | 0.5 | _   | ns   |  |  |
| t <sub>SC</sub>   | Chip Enable Set-Up Time         | 3.5 | _                     | 4   | _   | ns   |  |  |
| t <sub>HC</sub>   | Chip Enable Hold Time           | 0.5 | _                     | 0.5 | _   | ns   |  |  |
| t <sub>SW</sub>   | R/W Set-Up Time                 | 3.5 | _                     | 4   | _   | ns   |  |  |
| t <sub>HW</sub>   | R/W Hold Time                   | 0.5 | _                     | 0.5 | _   | ns   |  |  |
| t <sub>SD</sub>   | Input Data Set-Up Time          | 3.5 | _                     | 4   | _   | ns   |  |  |
| t <sub>HD</sub>   | Input Data Hold Time            | 0.5 | _                     | 0.5 | _   | ns   |  |  |
| t <sub>SAD</sub>  | ADS Set-Up Time                 | 3.5 | _                     | 4   | _   | ns   |  |  |
| t <sub>HAD</sub>  | ADS Hold Time                   | 0.5 | _                     | 0.5 | _   | ns   |  |  |
| t <sub>SCN</sub>  | CNTEN Set-Up Time               | 3.5 | _                     | 4   | _   | ns   |  |  |
| t <sub>HCN</sub>  | CNTEN Hold Time                 | 0.5 | _                     | 0.5 | _   | ns   |  |  |
| t <sub>SRST</sub> | CNTRST Set-Up Time              | 3.5 | _                     | 4   | _   | ns   |  |  |
| t <sub>HRST</sub> | CNTRST Hold Time                | 0.5 | _                     | 0.5 | _   | ns   |  |  |



# **Switching Characteristics** (continued)

Over the Operating Range

|                            |   | CY7C09569V/CY7C09579V |      |     |      |    |  |  |
|----------------------------|---|-----------------------|------|-----|------|----|--|--|
| Parameter                  | Description                                   | -1                    | 00   | -8  | Unit |    |  |  |
|                            |   | Min                   | Max  | Min | Max  |    |  |  |
| t <sub>OE</sub>            | Output Enable to Data Valid                   | _                     | 8    | _   | 9    | ns |  |  |
| t <sub>OLZ</sub> [10, 11]  | OE to Low Z                                   | 2                     | _    | 2   | _    | ns |  |  |
| t <sub>OHZ</sub> [10, 11]  | OE to High Z                                  | 1                     | 7    | 1   | 7    | ns |  |  |
| t <sub>CD1</sub>           | Clock to Data Valid – Flow-Through            | _                     | 12.5 | _   | 18   | ns |  |  |
| t <sub>CD2</sub>           | Clock to Data Valid – Pipelined               | _                     | 5    | _   | 6    | ns |  |  |
| t <sub>CA1</sub>           | Clock to Counter Address Valid – Flow-Through | _                     | 12.5 | _   | 18   | ns |  |  |
| t <sub>CA2</sub>           | Clock to Counter Address Valid – Pipelined    | _                     | 9    | _   | 10   | ns |  |  |
| t <sub>DC</sub>            | Data Output Hold After Clock HIGH             | 2                     | _    | 2   | _    | ns |  |  |
| t <sub>CKHZ</sub> [10, 11] | Clock HIGH to Output High Z                   | 2                     | 6    | 2   | 7    | ns |  |  |
| t <sub>CKLZ</sub> [10, 11] | Clock HIGH to Output Low Z                    | 2                     | -    | 2   | _    | ns |  |  |
| Port to Port D             | Port to Port Delays                           |                       |      |     |      |    |  |  |
| t <sub>CWDD</sub>          | Write Port Clock HIGH to Read Data Delay      | _                     | 30   | _   | 35   | ns |  |  |
| t <sub>CCS</sub>           | Clock to Clock Set-Up Time                    | _                     | 9    | _   | 10   | ns |  |  |

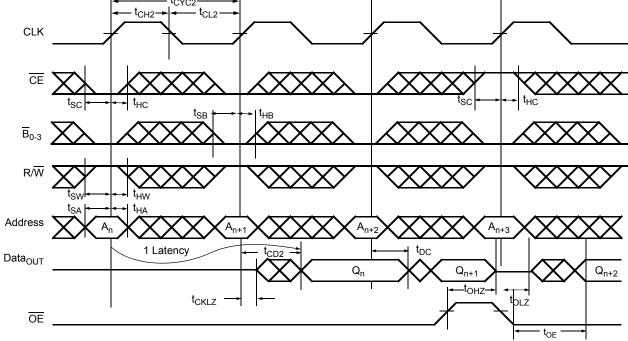
<sup>10.</sup> This parameter is guaranteed by design, but it is not production tested.11. Test conditions used are Load 2.



# **Switching Waveforms**

Figure 4. Read Cycle for Flow-Through Output ( $\overline{FT}/PIPE = V_{IL}$ ) [12, 13, 14, 15]  $t_{CL1}$ CLK Address Data<sub>OUT</sub> OE

Figure 5. Read Cycle for Pipelined Operation ( $\overline{\text{FT}}/\text{PIPE} = \text{V}_{\text{IH}}$ ) [12, 13, 14, 15]



- 12. <u>OE</u> is asynchronously controlled; all other inputs are synchronous to the rising clock edge.

  13. <u>ADS</u> = V<sub>IL</sub>, <u>CNTEN</u> = V<sub>IL</sub> and <u>CNTRST</u> = V<sub>IH</sub>.

  14. The output is disabled (high-impedance state) by <u>CE</u>=V<sub>IH</sub> following the next rising edge of the clock.

  15. Addresses do not have to be accessed sequentially since <u>ADS</u> = V<sub>IL</sub> constantly loads the address on the rising edge of the CLK. Numbers are for reference only.



Figure 6. Bus Match Read Cycle for Flow-Through Output ( $\overline{FT}/PIPE = V_{IL}$ ) [16, 17, 18, 19, 20]

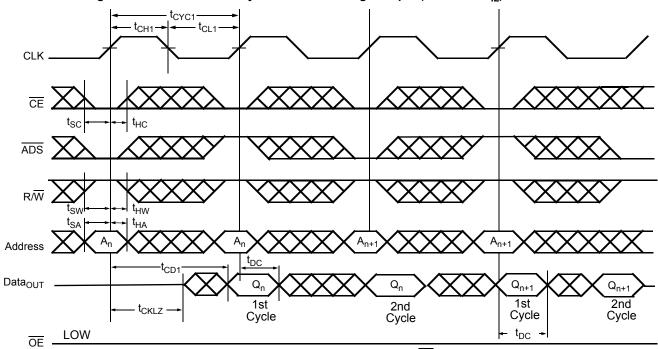
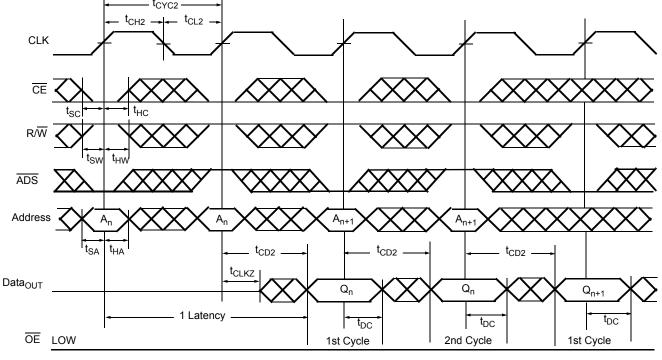


Figure 7. Bus Match Read Cycle for Pipelined Operation ( $\overline{\text{FT}}/\text{PIPE} = V_{\text{IH}}$ ) [16, 17, 18, 19, 20]



- Notes

  16. OE is asynchronously controlled; all other inputs are synchronous to the rising clock edge.

  17. The output is disabled (high-impedance state) by CE=V<sub>IH</sub> following the next rising edge of the clock.

  18. Timing shown is for x18 bus matching; x9 bus matching is similar with 4 cycles between address inputs.

  19. See table "Right Port Operation" for data output on first and subsequent cycles.

  20. CNTEN = V<sub>IL</sub>. In x9 and x18 Bus Matching Burst Mode operations (Write or Read), ADS can toggle on the rising edge of every clock cycle or it can be at V<sub>IH</sub> level all the time except when loading the initial external address (i.e. ADS = V<sub>IL</sub> only required when reading or writing the first Byte or Word).



Figure 8. Bank Select Pipelined Read [21, 22]

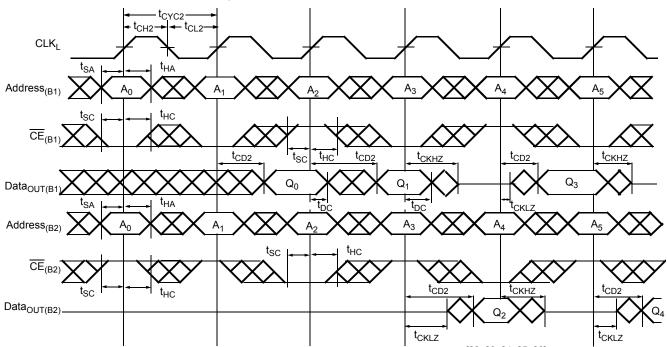
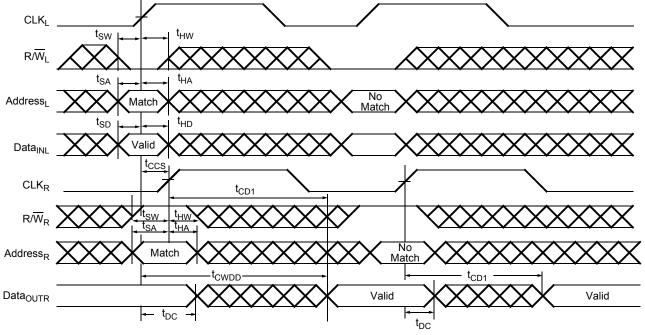


Figure 9. Left Port Write to Flow-Through Right Port Read [22, 23, 24, 25, 26]



- Notes

  21. In this depth expansion example, B1 represents Bank #1 and B2 is Bank #2; Each Bank consists of one Cypress dual-port device from this data sheet.

  ADDRESS<sub>(B21)</sub> = ADDRESS<sub>(B2)</sub>.

  22. B0 = B1 = B2 = B3 = BM = SIZE = ADS = CNTEN = V<sub>IL</sub>, CNTRST = V<sub>IH</sub>.

  23. The same waveforms apply for a right port write to flow-through left port read.

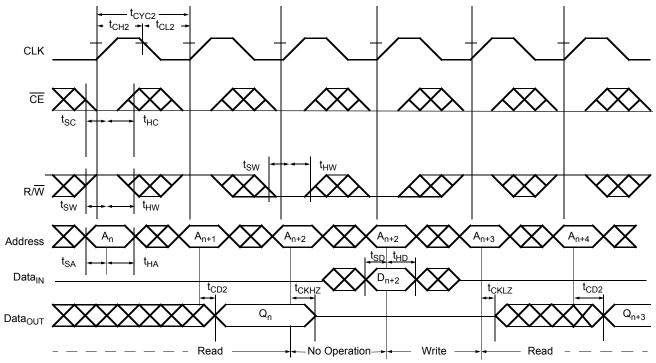
  24. CE = B0 = B1 = B2 = B3 = ADS = CNTEN=V<sub>IL</sub>; CNTRST = V<sub>IH</sub>.

  25. OE = V<sub>IL</sub> for the right port, which is being read from. OE = V<sub>IH</sub> for the left port, which is being written to.

  26. If t<sub>CCS</sub> ≤ maximum specified, then data from right port READ is not valid until the maximum specified for t<sub>CWDD</sub>. If t<sub>CCS</sub> > maximum specified, then data is not valid until t<sub>CCS</sub> + t<sub>CD1</sub> (t<sub>CWDD</sub> does not apply in this case).



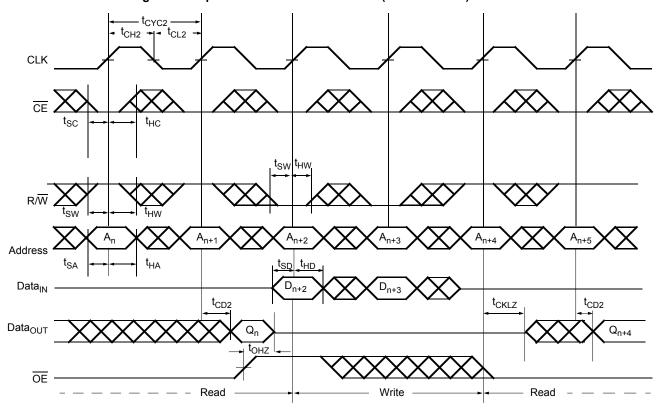
Figure 10. Pipelined Read-to-Write-to-Read ( $\overline{\text{OE}}$  =  $\text{V}_{\text{IL}}$ ) [27, 28, 29, 30]



<sup>27.</sup> Addresses do not have to be accessed sequentially since  $\overline{ADS} = V_{|L}$  constantly loads the address on the rising edge of the CLK. Numbers are for reference only. 28. Output state (HIGH, LOW, or High-Impedance) is determined by the previous cycle control signals.
29.  $\overline{CE} = \overline{ADS} = \overline{CNTEN} = V_{|L}$ ;  $\overline{CNTRST} = V_{|H}$ .
30. During "No Operation," data in memory at the selected address may be corrupted and should be rewritten to ensure data integrity.



Figure 11. Pipelined Read-to-Write-to-Read ( $\overline{\text{OE}}$  Controlled) [31, 32, 33, 34]



<sup>31.</sup> Test conditions used are Load 2.

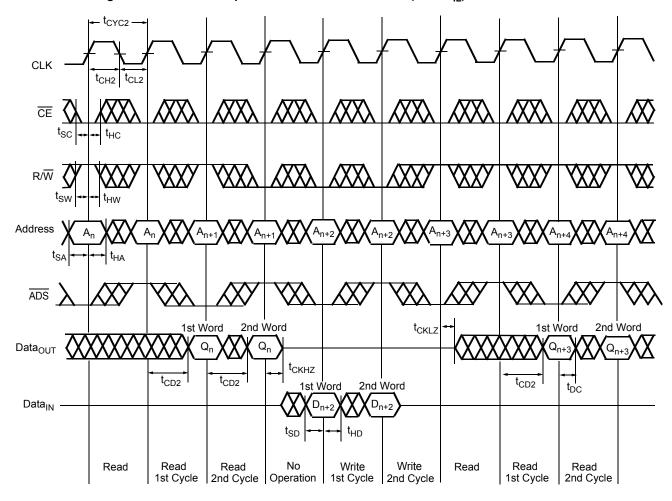
<sup>32.</sup> Output state (HIGH, LOW, or High-Impedance) is determined by the previous cycle control signals.

33.  $\overline{CE} = \overline{ADS} = \overline{CNTEN} = V_{IL}$ ;  $\overline{CNTRST} = V_{IH}$ .

34. During "No Operation," data in memory at the selected address may be corrupted and should be rewritten to ensure data integrity.



Figure 12. Bus Match Pipelined Read-to-Write-to-Read ( $\overline{OE}$  =  $V_{IL}$ ) [35, 36, 37, 38, 39, 40, 41]



<sup>35.</sup> Test conditions used are Load 2.

<sup>36.</sup> Timing shown is for x18 bus matching; x9 bus matching is similar with 4 cycles between address inputs.

<sup>37.</sup> See table "Right Port Operation" for data output on first and subsequent cycles.

<sup>8.</sup> CNTEN = V<sub>IL</sub>. In x9 and x18 Bus Matching Burst Mode operations (Write or Read), ADS can toggle on the rising edge of every clock cycle or it can be at V<sub>IH</sub> level all the time except when loading the initial external address (i.e. ADS = V<sub>IL</sub> only required when reading or writing the first Byte or Word).

<sup>39.</sup> CE = ADS = CNTEN = V<sub>IL</sub>; CNTRST = V<sub>IH</sub>.
40. During "No Operation," data in memory at the selected address may be corrupted and should be rewritten to ensure data integrity.

<sup>41.</sup> BM, SIZE, and BE must be reconfigured 1 cycle before operation is guaranteed. BM, SIZE, and BE should remain static for any particular port configuration.



Figure 13. Flow-Through Read-to-Write-to-Read ( $\overline{OE} = V_{IL}$ ) [42, 43, 44, 45, 46, 47]

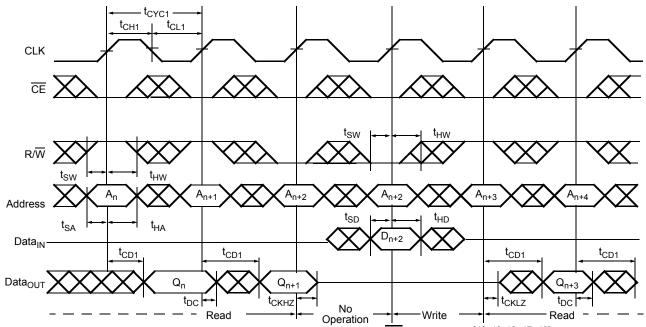
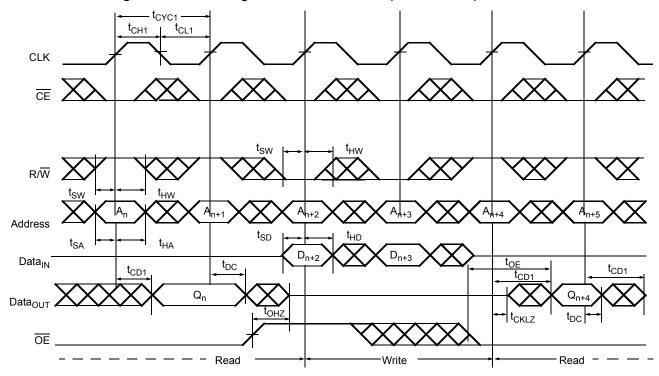


Figure 14. Flow-Through Read-to-Write-to-Read (OE Controlled) [42, 43, 46, 47, 48]



- 42. ADS = V<sub>IL</sub>, CNTEN = V<sub>IL</sub> and CNTRST = V<sub>IH</sub>.

  43. Addresses do not have to be accessed sequentially since ADS = V<sub>IL</sub> constantly loads the address on the rising edge of the CLK. Numbers are for reference only.

  44. Timing shown is for x18 bus matching; x9 bus matching is similar with 4 cycles between address inputs.

- 45. See table "Right Port Operation" for data output on first and subsequent cycles.

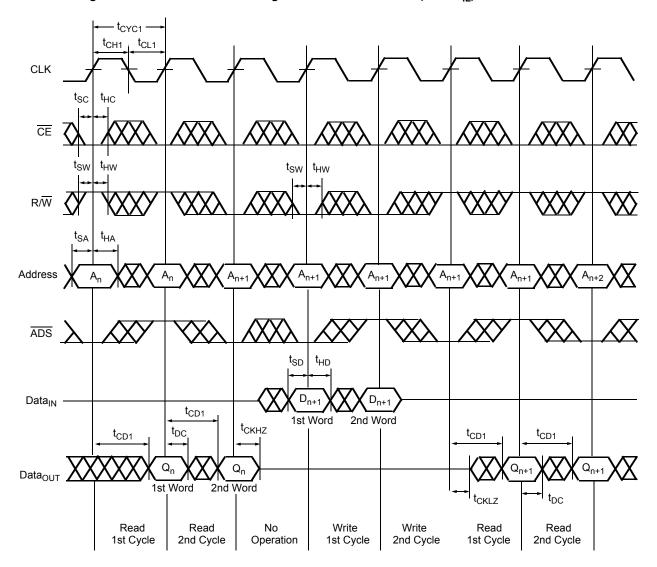
  46. CE = ADS = CNTEN = V<sub>II</sub>; CNTRST = V<sub>IH</sub>.

  47. During "No Operation," data in memory at the selected address may be corrupted and should be rewritten to ensure data integrity.

  48. Output state (HIGH, LOW, or High-Impedance) is determined by the previous cycle control signals.



Figure 15. Bus Match Flow-Through Read-to-Write-to-Read ( $\overline{OE} = V_{IL}$ ) [49, 50, 51, 52, 53, 54, 55]



- 49. Test conditions used are Load 2.
- 50. Timing shown is for x 18 bus matching; x 9 bus matching is similar with 4 cycles between address inputs.
- 50. Iming shown is for x 18 bus matching; x 9 bus matching is similar with 4 cycles between address inputs.

  51. See table "Right Port Operation" for data output on first and subsequent cycles.

  52. CNTEN = V<sub>IL</sub>. In x9 and x18 Bus Matching Burst Mode operations (Write or Read), ADS can toggle on the rising edge of every clock cycle or it can be at V<sub>IH</sub> level all the time except when loading the initial external address (i.e. ADS = V<sub>IL</sub> only required when reading or writing the first Byte or Word).

  53. CE = ADS = CNTEN = V<sub>IL</sub>; CNTRST = V<sub>IH</sub>.

  54. During "No Operation," data in memory at the selected address may be corrupted and should be rewritten to ensure data integrity.

  55. BM, SIZE, and BE must be reconfigured 1 cycle before operation is guaranteed. BM, SIZE, and BE should remain static for any particular port configuration.



Figure 16. Pipelined Read with Address Counter Advance [56]

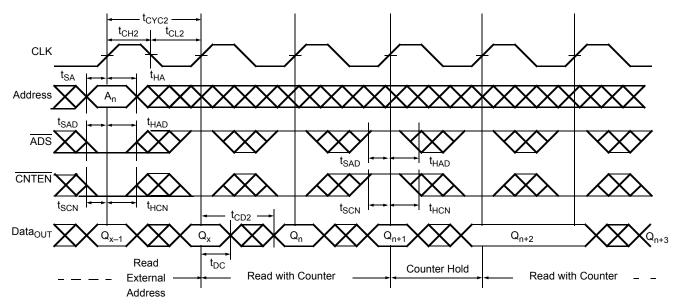
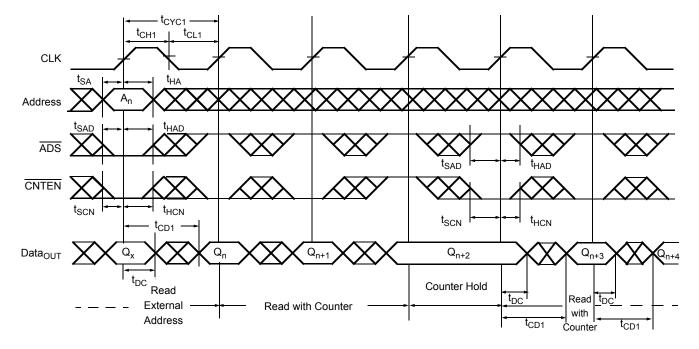


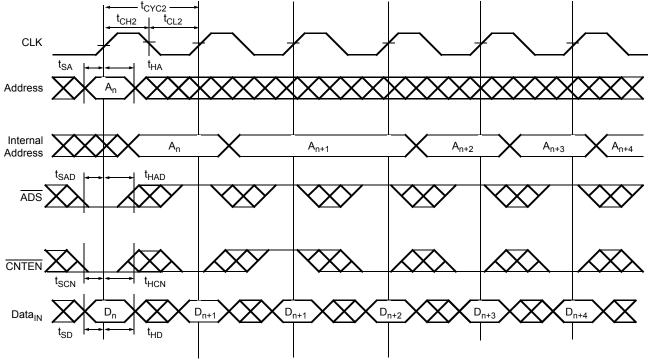
Figure 17. Flow-Through Read with Address Counter Advance [56]



Note  $56. \overline{CE} = \overline{OE} = V_{IL}; R/\overline{W} = \overline{CNTRST} = V_{IH}.$ 



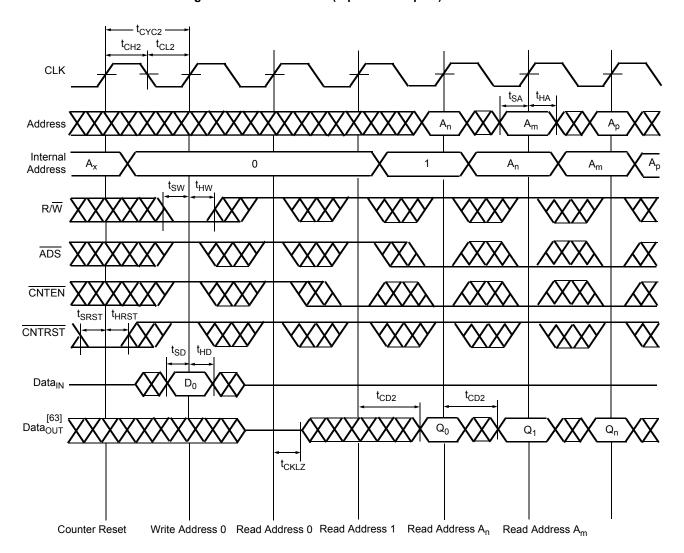
Figure 18. Write with Address Counter Advance (Flow-Through or Pipelined Outputs) [57, 58]



Write External Address Write with Counter Write Counter Hold Write with Counter



Figure 19. Counter Reset (Pipelined Outputs)  $^{[59,\,60,\,61,\,62,\,63]}$ 



<sup>59.</sup> Test conditions used are Load 2.

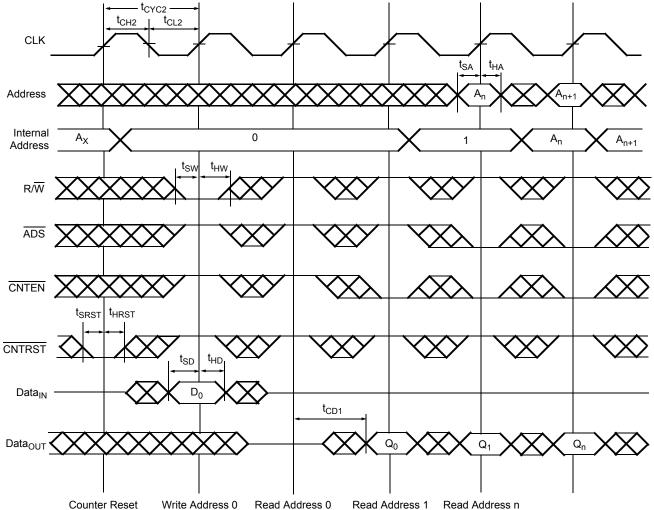
<sup>60.</sup> Output state (HIGH, LOW, or High-Impedance) is determined by the previous cycle control signals. 61.  $\overrightarrow{CE} = \overrightarrow{B0} = \overrightarrow{B1} = \overrightarrow{B2} = \overrightarrow{B3} = V_{IL}$ .

<sup>62.</sup> No dead cycle exists during counter reset. A READ or WRITE cycle may be coincidental with the counter reset.

<sup>63.</sup> Output state (HIGH, LOW, or High-Impedance) is determined by the previous cycle control signals. Ideally, DATA<sub>OUT</sub> should be in the High-Impedance state during a valid WRITÈ cycle.



Figure 20. Counter Reset (Flow-Through Outputs)  $^{[64,\ 65,\ 66,\ 67,\ 68]}$ 



<sup>64.</sup> Output state (HIGH, LOW, or High-Impedance) is determined by the previous cycle control signals.

<sup>65. &</sup>lt;u>During No Operation,</u> data in memory at the selected address may be corrupted and should be rewritten to ensure data integrity.

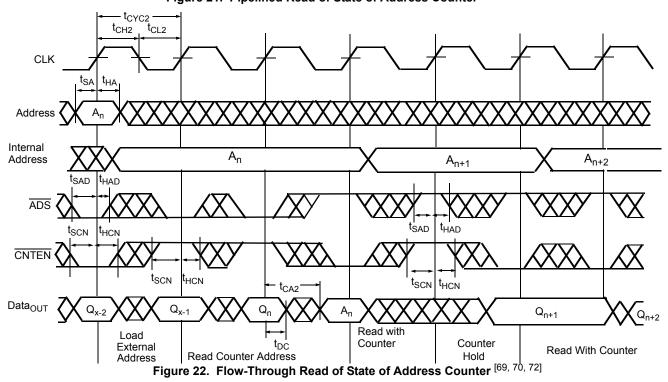
66. <u>CE</u> = <u>B0</u> = <u>B1</u> = <u>B2</u> = <u>B3</u> = V<sub>IL</sub>.

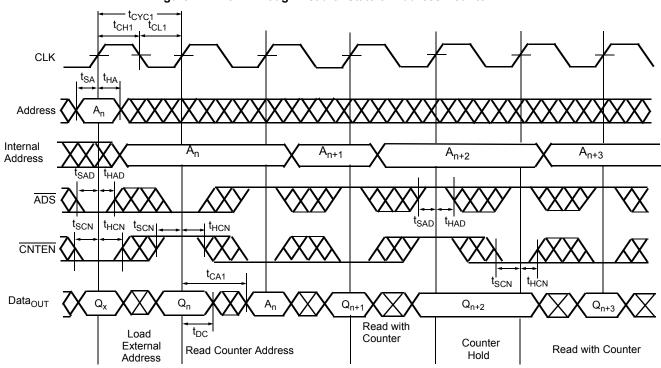
<sup>67.</sup> No dead cycle exists during counter reset. A READ or WRITE cycle may be coincidental with the counter reset.

68. Output state (HIGH, LOW, or High-Impedance) is determined by the previous cycle control signals. Ideally, DATA<sub>OUT</sub> should be in the High-Impedance state during a valid WRITE cycle.



Figure 21. Pipelined Read of State of Address Counter [69, 70, 71]





<sup>69.</sup> CE = OE = V<sub>IL</sub>; R/W = CNTRST = V<sub>IH</sub>.
70. When reading ADDRESS<sub>OUT</sub> in x 9 Bus Match mode, readout of A<sub>N</sub> is extended by 1 cycle.

<sup>71.</sup> For Pipelined address counter read, signals from address counter operation table from must be valid for 2 consecutive cycles for x 36 and x 18 mode and for 3 consecutive cycles for x 9 mode.

<sup>72.</sup> For flow-through address counter read, signals from address counter operation table must be valid for consecutive cycles for x 36.



# Read/Write and Enable Operation

The Read/Write and Enable Operation is described as follows. [73, 74, 75]

|    | Inp | uts |     | Outputs                             | Operation                  |
|----|-----|-----|-----|-------------------------------------|----------------------------|
| OE | CLK | CE  | R/W | I/O <sub>0</sub> –I/O <sub>35</sub> | Operation                  |
| X  | 7   | Н   | X   | High Z                              | Deselected <sup>[76]</sup> |
| X  | 7   | L   | L   | D <sub>IN</sub>                     | Write                      |
| L  | 7   | L   | Н   | D <sub>OUT</sub>                    | Read <sup>[76]</sup>       |
| Н  | Х   | L   | Х   | High Z                              | Outputs disabled           |

# **Address Counter Control Operation**

The Address Counter Control Operation is described as follows. [73, 77]

| Address        | Previous<br>Address | CLK | OE | R/W | ADS | CNTEN | CNTRST | Mode        | Operation  |
|----------------|---------------------|-----|----|-----|-----|-------|--------|-------------|--|
| X              | Х                   | 4   | Х  | Х   | Х   | Х     | L      | Reset       | Counter reset                                      |
| A <sub>n</sub> | Х                   | 7   | Х  | Х   | L   | L     | Н      | Load        | Address load into counter                          |
| A <sub>n</sub> | A <sub>n</sub>      | 7   | L  | Н   | L   | Н     | Н      | Hold + Read | External address blocked – counter address readout |
| Х              | A <sub>n</sub>      | 7   | Х  | Х   | Н   | Н     | Н      | Hold        | External address blocked – counter disabled        |
| Х              | A <sub>n</sub>      | 7   | Х  | Х   | Н   | L     | Н      | Increment   | Counter increment                                  |

<sup>73. &</sup>quot;X" = "Don't Care," "H" = V<sub>IH</sub>, "L" = V<sub>IL</sub>.
74. ADS, CNTEN, CNTRST = "Don't Care."
75. OE is an asynchronous input signal.
76. When CE changes state In the pipelined mode, deselection and read happen in the following clock cycle.
77. Counter operation is independent of CE.



# **Right Port Configuration**

The Right Port Configuration is described as follows. [78, 79]

| ВМ | SIZE | Configuration | I/O Pins used         |
|----|------|---------------|-----------------------|
| 0  | 0    | × 36          | I/O <sub>0R-35R</sub> |
| 1  | 0    | × 18          | I/O <sub>0R-17R</sub> |
| 1  | 1    | × 9           | I/O <sub>0R-8R</sub>  |

# **Right Port Operation**

The Right Port Operation is described as follows. [80]

| Configuration | BE | Data on 1st Cycle    | Data on 2nd Cycle    | Data on 3rd Cycle    | Data on 4th Cycle    |
|---------------|----|----------------------|----------------------|----------------------|----------------------|
| × 18          | 0  | Q <sub>0R-17R</sub>  | Q <sub>18R-35R</sub> | _                    | _                    |
| × 18          | 1  | Q <sub>18R-35R</sub> | Q <sub>0R-17R</sub>  | _                    | _                    |
| × 9           | 0  | Q <sub>0R-8R</sub>   | Q <sub>9R-17R</sub>  | Q <sub>18R-26R</sub> | Q <sub>27R-35R</sub> |
| × 9           | 1  | Q <sub>27R-35R</sub> | Q <sub>18R-26R</sub> | Q <sub>9R-17R</sub>  | Q <sub>0R-8R</sub>   |

## **Readout of Internal Address Counter**

The Readout of Internal Address Counter is described as follows. [81]

| Configuration   | Address on 1st Cycle    | I/O Pins used on 1st Cycle | Address on 2nd Cycle       | I/O Pins used on 2nd Cycle |
|-----------------|-------------------------|----------------------------|----------------------------|----------------------------|
| Left Port × 36  | A <sub>0L-14L</sub>     | I/O <sub>3L-17L</sub>      | _                          | -                          |
| Right Port × 36 | A <sub>0R-14R</sub>     | I/O <sub>3R-17R</sub>      | -                          | _                          |
| Right Port × 18 | WA, A <sub>0R-14R</sub> | I/O <sub>2R-17R</sub>      | -                          | _                          |
| Right Port × 9  | A <sub>6R-14R</sub>     | I/O <sub>0R-8R</sub>       | BA, WA, A <sub>0R-5R</sub> | I/O <sub>1R-8R</sub>       |

## **Left Port Operation**

The Left Port Operation is described as follows.

| Control Pin | Effect                            |
|-------------|-----------------------------------|
| B0          | I/O <sub>0-8</sub> Byte Control   |
| B1          | I/O <sub>9-17</sub> Byte Control  |
| B2          | I/O <sub>18–26</sub> Byte Control |
| B3          | I/O <sub>27–35</sub> Byte Control |

#### Notes

78. BM, SIZE, and BE must be reconfigured 1 cycle before operation is guaranteed. BM, SIZE, and BE should remain static for any particular port configuration.

79. In x36 mode, BE input is a "Don't Care."

80. DQ represents data output of the chip.

81. x18 and x9 configuration apply to right port only.



## **Counter Operation**

The CY7C09569V/CY7C09579V Dual-Port RAM (DPRAM) contains on-chip address counters (one for each port) for the synchronous members of the product family. Besides the main × 36 format, the right port allows bus matching (× 18 or × 9, user-selectable). An internal sub-counter provides the extra addresses required to sequence out the 36-bit word in 18-bit or 9-bit increments. The sub-counter counts up in the "Little Endian" mode, and counts down if the user has chosen the "Big Endian" mode. The address counter is required to be in increment mode in order for the sub-counter to sequence out the second word (in × 18 mode) or the remaining three bytes (in × 9 mode).

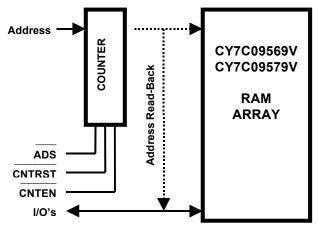
For a  $\times$  36 format (the only active format on the left port), each address counter in the CY7C09579V uses addresses (A<sub>0-14</sub>).

For the right port (allowing for the bus-matching feature), a maximum of two address bits (out of a 2-bit sub-counter) are added.

- ADS<sub>L/R</sub> (pin #23/86) is a port's address strobe, allowing the loading of that port's burst counters if the corresponding CNTEN<sub>L/R</sub> pin is active as well.
- 2. CNTEN<sub>L/R</sub> (pin #25/84) is a port's count enable, provided to stall the operation of the address input and utilize the internal address generated by the internal counter for fast interleaved memory applications; when asserted, the address counter will increment on each positive transition of that port's clock signal.
- 3. CNTRST<sub>I /R</sub> (pin #24/85) is a port's burst counter reset.

A new read-back (Hold+Read Mode) feature has been added, which is different between the left and right port due to the bus matching feature provided only for the right port. In read-back mode the internal address of the counter will be read from the data I/Os as shown in Figure 23.

Figure 23. Counter Operation Diagram

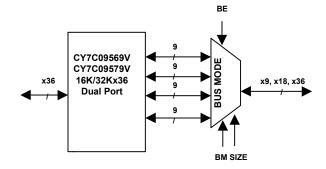


## **Bus Match Operation**

The right port of the CY7C09569V/CY7C09579V 16K/32K × 36 dual-port SRAM can be configured in a 36-bit long-word, 18-bit

word, or 9-bit byte format for data I/O. The data lines are divided into four lanes, each consisting of 9 bits (byte-size data lines).

Figure 24. Bus Match Operation Diagram



The Bus Match Select (BM) pin works with Bus Size Select (SIZE) and Big Endian Select (BE) to select the bus width (long-word, word, or byte) and data sequencing arrangement for the right port of the dual-port device. A logic LOW applied to both the Bus Match Select (BM) pin and to the Bus Size Select (SIZE) pin will select long-word (36-bit) operation. A logic HIGH level applied to the Bus Match Select (BM) pin will enable whether byte or word bus width operation on the right port I/Os depending on the logic level applied to the SIZE pin. The level of Bus Match Select (BM) must be static throughout normal device operation.

The Bus Size Select (SIZE) pin selects either a byte or word data arrangement on the right port when the Bus Match Select (BM) pin is HIGH. A logic HIGH on the SIZE pin when the BM pin is HIGH selects a byte bus (9-bit) data arrangement. A logic LOW on the SIZE pin when the BM pin is HIGH selects a word bus (18-bit) data arrangement. The level of the Bus Size Select (SIZE) must also be static throughout normal device operation.

The Big Endian Select (BE) pin is a multiple-function pin during word or byte bus selection (BM = 1). BE is used in Big Endian Select mode to determine the order by which bytes (or words) of data are transferred through the right data port. A logic LOW on the BE pin will select Little Endian data sequencing arrangement and a logic HIGH on the BE pin will select a Big Endian data sequencing arrangement. Under these circumstances, the level on the BE pin should be static throughout dual-port operation.

#### Long-Word (36-bit) Operation

Bus Match Select (BM) and Bus Size Select (SIZE) set to a logic LOW will enable standard cycle long-word (36-bit) operation. In this mode, the right port's I/O operates essentially in an identical fashion to the left port of the dual-port SRAM. However no Byte Select control is available. All 36 bits of the long-word are shifted into and out of the right port's I/O buffer stages. All read and write timing parameters may be identical with respect to the two data ports. When the right port is configured for a long-word size, Big-Endian Select (BE) pin has no application and their inputs are "Don't Care" [82] for the external user.

#### Note

<sup>82.</sup> Even though a logic level applied to a "Don't Care" input will not change the logical operation of the dual-port, inputs that are temporarily a "Don't Care" (along with unused inputs) must not be allowed to float. They must be forced either HIGH or LOW.



### Word (18-bit) Operation

Word (18-bit) bus sizing operation is enabled when Bus Match Select (BM) is set to a logic HIGH and the Bus Size Select (SIZE) pin is set to a logic LOW. In this mode, 18 bits of data are ported through  $I/O_{0R-17R}$ . The level applied to the Big Endian (BE) pin determines the right port data I/O sequencing order (Big Endian or Little Endian).

During word (18-bit) bus size operation, a logic LOW applied to the BE pin will select Little Endian operation. In this case, the least significant data word is read from the right port first or written to the right port first. A logic HIGH on the BE pin during word (18-bit) bus size operation will select Big Endian operation resulting in the most significant data word being transferred through the right port first. Internally, the data will be stored in the appropriate 36-bit LSB or MSB I/O memory location. Device operation requires a minimum of two clock cycles to read or write during word (18-bit) bus size operation. An internal sub-counter automatically increments the right port multiplexer control when Little or Big Endian operation is in effect.

### Byte (9-bit) Operation

Byte (9-bit) bus sizing operation is enabled when Bus Match Select (BM) is set to a logic HIGH and the Bus Size Select (SIZE) pin is set to a logic HIGH. In this mode, 9 bits of data are ported through  $I/O_{0R-8R}$ .

Big Endian and Little Endian data sequencing is available for dual-port operation. The level applied to the Big Endian pin (BE) under these circumstances will determine the right port data I/O sequencing order (Big or Little Endian). A logic LOW applied to the BE pin during byte (9-bit) bus size operation will select Little Endian operation. In this case, the least significant data byte is read from the right port first or written to the right port first. A logic HIGH on the BE pin during byte (9-bit) bus size operation will select Big Endian operation resulting in the most significant data word to be transferred through the right port first. Internally, the data will be stored in the appropriate 36-bit LSB or MSB I/O memory location. Device operation requires a minimum of four clock cycles to read or write during byte (9-bit) bus size operation. An internal sub-counter automatically increments the right port multiplexer control when Little or Big Endian operation is in effect. When transferring data in byte (9-bit) bus match format, the unused I/O pins  $(I/O_{9R-35R})$  are three-stated.



# **Ordering Information**

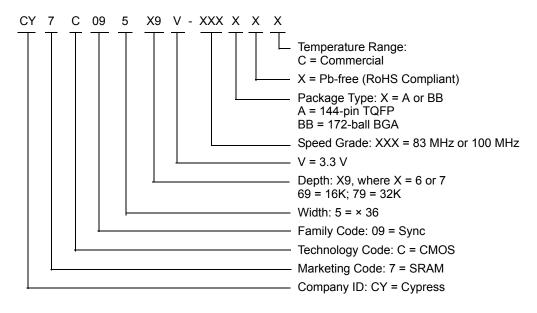
### 16K × 36 3.3 V Synchronous Dual-Port SRAM

| Speed<br>(MHz) | Ordering Code         | Package<br>Name | Package Type           | Operating<br>Range |
|----------------|-----------------------|-----------------|------------------------|--------------------|
| 100            | 100 CY7C09569V-100AXC |                 | 144-pin TQFP (Pb-free) | Commercial         |

### 32K × 36 3.3 V Synchronous Dual-Port SRAM

| Speed<br>(MHz) | Ordering Code     | Package<br>Name | Package Type           | Operating<br>Range |
|----------------|-------------------|-----------------|------------------------|--------------------|
| 100            | CY7C09579V-100AXC | A144            | 144-pin TQFP (Pb-free) | Commercial         |
|                | CY7C09579V-100BBC | BB172           | 172-ball BGA           |                    |
| 83             | CY7C09579V-83BBC  | BB172           | 172-ball BGA           | Commercial         |

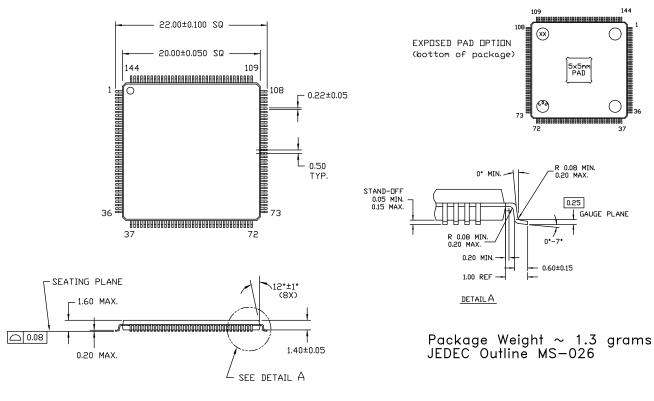
### **Ordering Code Definitions**





# **Package Diagrams**

Figure 25. 144-pin TQFP (20 × 20 × 1.4 mm) A144SA Package Outline, 51-85047



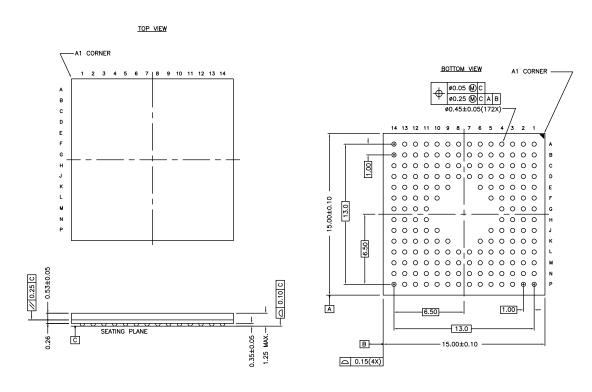
(DIMENSIONS ARE IN MILLIMETERS)

51-85047 \*E



# Package Diagrams (continued)

Figure 26. 172-ball FBGA (15 × 15 × 1.25 mm) BB172 Package Outline, 51-85114



Package Weight — Refer to PMDD spec.

51-85114 \*E



# **Acronyms**

| Acronym | Description                             |  |  |
|---------|---|--|--|
| ADS     | Address Strobe                          |  |  |
| BGA     | Ball Grid Array                         |  |  |
| CE      | Chip Enable                             |  |  |
| CMOS    | Complementary Metal Oxide Semiconductor |  |  |
| CNTEN   | Count Enable                            |  |  |
| CNTRST  | Counter Reset                           |  |  |
| I/O     | Input/Output                            |  |  |
| LSB     | Least Significant Bit                   |  |  |
| MSB     | Most Significant Bit                    |  |  |
| OE      | Output Enable                           |  |  |
| SRAM    | Static Random Access Memory             |  |  |
| TQFP    | Thin Quad Flat Pack                     |  |  |
| TTL     | Transistor-Transistor Logic             |  |  |

# **Document Conventions**

## **Units of Measure**

| Symbol | Unit of Measure |  |
|--------|-----------------|--|
| °C     | degree Celsius  |  |
| MHz    | megahertz       |  |
| μΑ     | microampere     |  |
| mA     | milliampere     |  |
| mm     | millimeter      |  |
| ns     | nanosecond      |  |
| pF     | picofarad       |  |
| V      | volt            |  |
| W      | watt            |  |



# **Document History Page**

| Document Title: CY7C09569V/CY7C09579V, 3.3 V, 16K/32K × 36 FLEx36 <sup>®</sup> Synchronous Dual-Port Static RAM<br>Document Number: 38-06054 |         |                    |                    |   |
|--|---------|--------------------|--------------------|---|
| Rev.   | ECN     | Orig. of<br>Change | Submission<br>Date | Description of Change   |
| **   | 110213  | SZV                | 12/16/2001         | Change from Spec number: 38-00743 to 38-06054.  |
| *A   | 122304  | RBI                | 12/27/2002         | Updated Maximum Ratings (Added Note 6 and referred the same note in "Maximum Ratings").   |
| *B   | 349775  | RUY                | 04/18/2005         | Updated Ordering Information (Updated part numbers).  |
| *C   | 2897215 | RAME               | 03/22/2010         | Updated Ordering Information (Updated part numbers). Updated Package Diagrams.  |
| *D   | 3110406 | ADMU               | 12/14/2010         | Added Ordering Code Definitions under Ordering Information. Minor edits. Updated to new template.   |
| *E   | 3162642 | ADMU               | 02/04/2011         | Updated Selection Guide (Removed speed bin -67 related information). Updated Operating Range (Removed Industrial Temperature Range information). Updated Electrical Characteristics (Removed speed bin -67 related information). Updated Switching Characteristics (Removed speed bin -67 related information). Added Acronyms and Units of Measure.  |
| *F   | 3352391 | ADMU               | 08/23/2011         | Updated Package Diagrams (Spec 51-85047 (Changed revision from *C to *D)).  |
| *G   | 3702863 | SMCH               | 08/20/2012         | Replaced Logic '0' with Logic LOW in all instances across the document. Replaced Logic '1' with Logic HIGH in all instances across the document. Updated Logic Block Diagram (Aligned all the objects correctly). Updated Switching Waveforms (Updated Figure 18 (Aligned the naming of objects correctly), updated Figure 19 (Aligned the naming of objects correctly) updated Figure 20 (Aligned the naming of objects correctly). Updated Right Port Operation (Updated the columns Data on 1st Cycle, Data on 2nd Cycle, Data on 3rd Cycle and Data on 4th Cycle). Updated Bus Match Operation (Updated Byte (9-bit) Operation (description) Updated Package Diagrams (Spec 51-85114 (Changed revision from *C to *D)). |
| *H   | 3859909 | SMCH               | 01/07/2013         | Updated Ordering Information (Updated part numbers). Updated Package Diagrams: spec 51-85114 – Changed revision from *D to *E.  |
| *  | 4112555 | SMCH               | 09/03/2013         | Updated to new template. Completing Sunset Review.  |
| *J   | 4580622 | SMCH               | 11/26/2014         | Updated Functional Description: Added "For a complete list of related documentation, click here." at the end.   |
| *K   | 5438809 | NILE               | 09/16/2016         | Updated Package Diagrams:<br>spec 51-85047 – Changed revision from *D to *E.<br>Updated to new template.<br>Completing Sunset Review.   |
| *L   | 5840462 | NILE               | 08/01/2017         | Updated Ordering Information: Updated part numbers. Updated to new template. Completing Sunset Review.  |



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### **Cypress Developer Community**

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